

## Complementary Silicon High-Power Transistors

... PowerBase™ complementary transistors designed for high power audio, stepping motor and other linear applications. These devices can also be used in power switching circuits such as relay or solenoid drivers, dc-to-dc converters, inverters, or for inductive loads requiring higher safe operating area than the 2N3055 and MJ2955.

- Current-Gain — Bandwidth-Product @  $I_C = 1.0 \text{ Adc}$   
 $f_T = 0.8 \text{ MHz (Min) - NPN}$   
 $= 2.2 \text{ MHz (Min) - PNP}$
- Safe Operating Area — Rated to 60 V and 120 V, Respectively

### \*MAXIMUM RATINGS

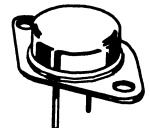
Rating	Symbol	2N3055A MJ2955A	MJ15015 MJ15016	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	120	Vdc
Collector-Base Voltage	$V_{CBO}$	100	200	Vdc
Collector-Emitter Voltage Base Reversed Biased	$V_{CEV}$	100	200	Vdc
Emitter-Base Voltage	$V_{EBO}$	7.0		Vdc
Collector Current — Continuous	$I_C$	15		Adc
Base Current	$I_B$	7.0		Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	115 0.65	180 1.03	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200		$^\circ\text{C}$

### THERMAL CHARACTERISTICS

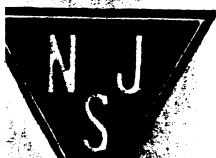
Characteristic	Symbol	Max	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.52	0.98	$^\circ\text{C/W}$

**NPN**  
**2N3055A**  
**MJ15015**  
**MJ2955A**  
**PNP**  
**MJ15016**

**15 AMPERE**  
**COMPLEMENTARY**  
**SILICON**  
**POWER TRANSISTORS**  
**60, 120 VOLTS**  
**115, 180 WATTS**



**CASE 1-07**  
**TO-204AA**  
**(TO-3)**



**2N3055A MJ15015 MJ2955A MJ15016**

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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**OFF CHARACTERISTICS (1)**

*Collector-Emitter Sustaining Voltage ( $I_C = 200 \text{ mAdc}$ , $I_B = 0$ )	2N3055A, MJ2955A MJ15015, MJ15016	$V_{CEO(sus)}$	60 120	— —	Vdc
Collector Cutoff Current ( $V_{CE} = 30 \text{ Vdc}$ , $V_{BE(off)} = 0 \text{ Vdc}$ ) ( $V_{CE} = 60 \text{ Vdc}$ , $V_{BE(off)} = 0 \text{ Vdc}$ )	2N3055A, MJ2955A MJ15015, MJ15016	$I_{CEO}$	— —	0.7 0.1	mAdc
*Collector Cutoff Current ( $V_{CEV} = \text{Rated Value}$ , $V_{BE(off)} = 1.5 \text{ Vdc}$ )	2N3055A, MJ2955A MJ15015, MJ15016	$I_{CEV}$	— —	5.0 1.0	mAdc
Collector Cutoff Current ( $V_{CEV} = \text{Rated Value}$ , $V_{BE(off)} = 1.5 \text{ Vdc}$ , $T_C = 150^\circ\text{C}$ )	2N3055A, MJ2955A MJ15015, MJ15016	$I_{CEV}$	— —	30 6.0	mAdc
Emitter Cutoff Current ( $V_{EB} = 7.0 \text{ Vdc}$ , $I_C = 0$ )	2N3055A, MJ2955A MJ15015, MJ15016	$I_{EBO}$	— —	5.0 0.2	mAdc

**\*SECOND BREAKDOWN**

Second Breakdown Collector Current with Base Forward Biased ( $t = 0.5 \text{ s non-repetitive}$ ) ( $V_{CE} = 60 \text{ Vdc}$ )	2N3055A, MJ2955A MJ15015, MJ15016	$I_{s/b}$	1.95 3.0	— —	Adc
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**\*ON CHARACTERISTICS (1)**

DC Current Gain ( $I_C = 4.0 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ ) ( $I_C = 4.0 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$ ) ( $I_C = 10 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$ )		$h_{FE}$	10 20 5.0	70 70 —	—
Collector-Emitter Saturation Voltage ( $I_C = 4.0 \text{ Adc}$ , $I_B = 400 \text{ mAdc}$ ) ( $I_C = 10 \text{ Adc}$ , $I_B = 3.3 \text{ Adc}$ ) ( $I_C = 15 \text{ Adc}$ , $I_B = 7.0 \text{ Adc}$ )		$V_{CE(sat)}$	— — —	1.1 3.0 5.0	Vdc
Base-Emitter On Voltage ( $I_C = 4.0 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$ )		$V_{BE(on)}$	0.7	1.8	Vdc

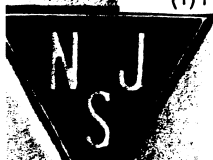
**\*DYNAMIC CHARACTERISTICS**

Current-Gain — Bandwidth Product ( $I_C = 1.0 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$ , $f = 1.0 \text{ MHz}$ )	2N3055A, MJ15015 MJ2955A, MJ15016	$f_T$	0.8 2.2	6.0 18	MHz
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )		$C_{ob}$	60	600	pF

**\*SWITCHING CHARACTERISTICS (2N3055A only)**

RESISTIVE LOAD					
Delay Time	$(V_{CC} = 30 \text{ Vdc}$ , $I_C = 4.0 \text{ Adc}$ , $I_{B1} = I_{B2} = 0.4 \text{ Adc}$ , $t_p = 25 \mu\text{s}$ Duty Cycle $\leq 2\%$ )	$t_d$	—	0.5	$\mu\text{s}$
Rise Time		$t_r$	—	4.0	$\mu\text{s}$
Storage Time		$t_s$	—	3.0	$\mu\text{s}$
Fall Time		$t_f$	—	6.0	$\mu\text{s}$

(1) Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .



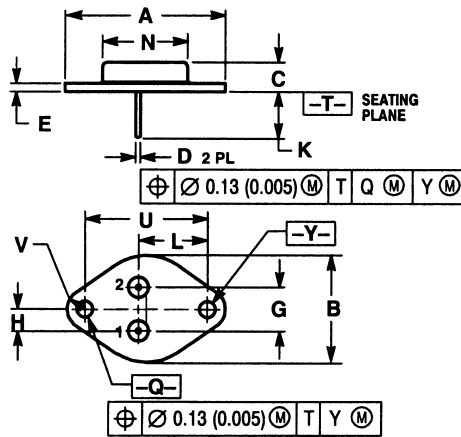
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2N3055A MJ15015 MJ2955A MJ15016

## PACKAGE DIMENSIONS



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:  
 PIN 1. BASE  
 2. EMITTER  
 CASE: COLLECTOR

